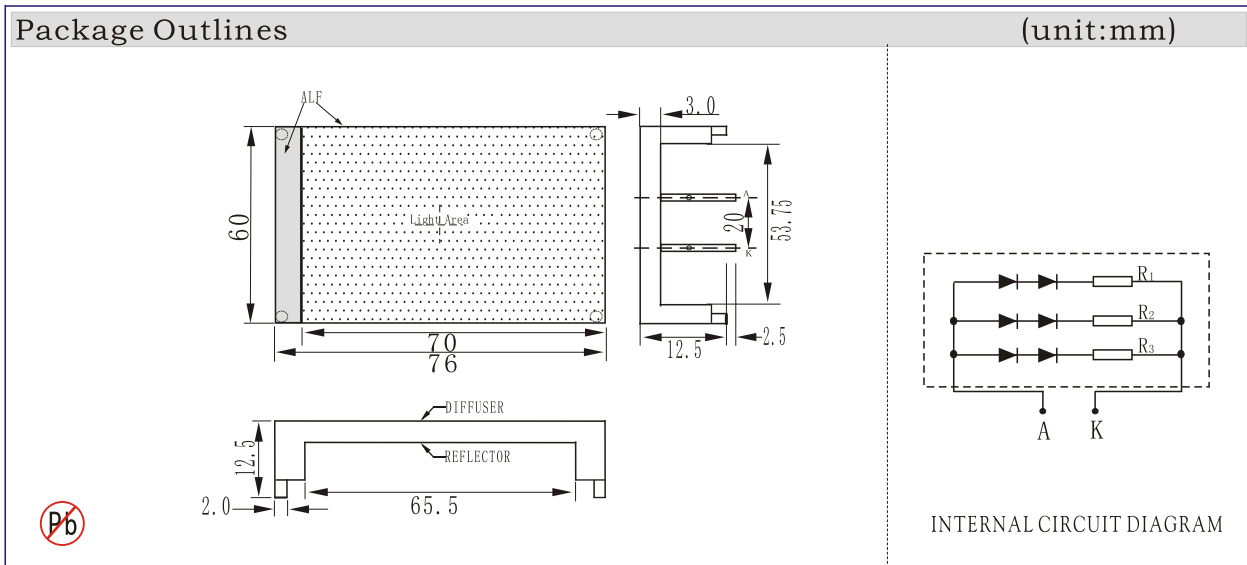


Part Number	Emitting Material	Wave Length λ_D (nm)	Emitting Color	(If=20mA)		
				V_F (v)		I_V (mcd)
				Typ.	Max.	Typ.
CLB-7660-△R	GaAlAs	690	Red	2.3	2.5	150
CLB-7660-△O	GaAsP/GaP	610	Orange	2.3	2.5	200
CLB-7660-△G	AlGaInP	520	Green	3.2	3.8	280
CLB-7660-△Y	GaAsP/GaP	585	Yellow	2.3	2.5	180
CLB-7660-△B	GaN	465	Blue	3.0	3.8	245
CLB-7660-△W	GaN	—	White	3.5	4.0	500

ABSOLUTE MAXIMUM RATINGS (Ta=+25°C)

PARAMETER	SYMBOL	RATING	UNIT
Forward Current	I_F	20	mA
Forward Pulse Current	$I_{F(Peak)}$	100	mA
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	-20~+85	°C
Storage Temperature	T_{Stg}	-40~+85	°C
Soldering Hear (5s)	T_{Sol}	260	°C
Power Dissipation	P_d	540 (DC:9V)	mW



Remark : 1. “△” represents Internal Circuit Feature: A、C、E...Common Cathode, B、D、F...Common Anode.
 2. “□” represents LED Emitted Color.
 3. All dimensions are in millimeters, tolerance is 0.25mm unless otherwise noted.
 4. Above specification is measured by CHANGLI's test instrument and may be changed without notice.
 5. Supplier will reserve authority on material change for above specification.